3SK143

Silicon N-Channel 4-pin MOS FET

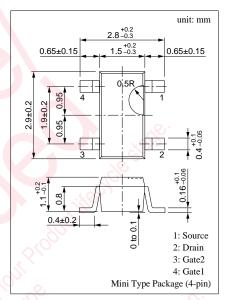
For UHF high-gain and low-noise amplification

■ Features

- Low noise-figure (NF)
- Large power gain PG
- Mini-type package, allowing downsizing of the sets and automatic insertion through the tape/magazine packing.

■ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Drain to Source voltage	V _{DS}	15	V
Gate 1 to Source voltage	V _{G1S}	±8	V
Gate 2 to Source voltage	V _{G2S}	±8	V
Drain current	I_{D}	±30	mA
Allowable power dissipation	$P_{\rm D}$	200	mW
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Marking Symbol: 3D

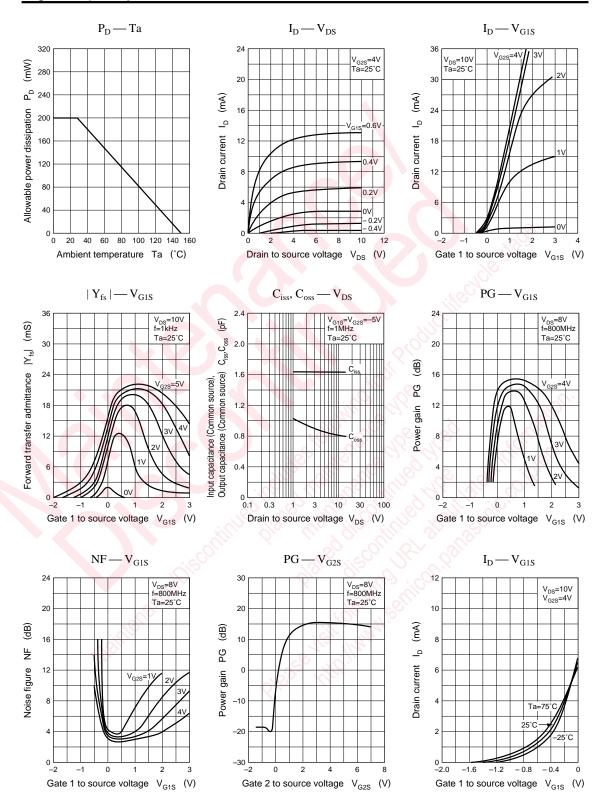
■ Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{\rm DSS}^{*2}$	$V_{DS} = 10V, V_{GS} = 0, V_{G2S} = 4V$	0.2	5, 50	13	mA
Gate 1 cut-off current	I _{G1SS}	$V_{DS} = V_{G2S} = 0, V_{G1S} = \pm 8V$	1. 3.	100	±20	nA
Gate 2 cut-off current	I_{G2SS}	$V_{DS} = V_{G1S} = 0, V_{G2S} = \pm 8V$	M.	20,	±20	nA
Drain to Source voltage	V_{DSX}^{*1}	$I_D = 100\mu A, V_{G1S} = -5V, V_{G2S} = 0$	15			V
Gate 1 to Source cut-off voltage	V_{GISC}	$V_{DS} = 10V, V_{G2S} = 4V, I_D = 100\mu A$	-3		0	V
Gate 2 to Source cut-off voltage	V_{G2SC}	$V_{DS} = 10V, V_{G2S} = 0, I_{D} = 100\mu A$	-1		2	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10V, I_D = 10mA, V_{G2S} = 4V, f = 1kHz$	12	20	28	mS
Input capacitance (Common Source)	C _{iss}	V - 10V V - V - 5V	1.4	1.9	2.4	pF
Output capacitance (Common Source)	Coss	$V_{DS} = 10V, V_{G1S} = V_{G2S} = -5V$ f = 1MHz	0.6	0.9	1.2	pF
Reverse transfer capacitance (Common Source)	C _{rss}	I = IMIHZ		0.02		pF
Power gain	PG	$V_{DS} = 8V, I_{D} = 8mA, V_{G2S} = 3V$	13	15		dB
Noise figure	NF	f = 800MHz			5	dB

 $^{^{*1}}$ $R_D=56\Omega$ and $R_S=270\Omega$

^{*2} I_{DSS} rank classification

Rank	0	P	Q
I _{DSS} (mA)	0.2 to 1.5	0.5 to 4	3 to 13
Marking Symbol	3DO	3DP	3DQ



2 Panasonic

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